

## N-Channel Super Junction Power MOSFET IV

### General Description

The series of devices use advanced trench gate super junction technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

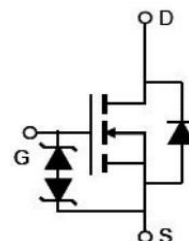
### Features

- New technology for high voltage device
- Low on-resistance and low conduction losses
- Small package
- Ultra Low Gate Charge cause lower driving requirements
- 100% Avalanche Tested
- ROHS compliant

### Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

|                          |      |            |
|--------------------------|------|------------|
| $V_{DS \min @ T_{jmax}}$ | 550  | V          |
| $R_{DS(ON)TYP.}$         | 180  | m $\Omega$ |
| $I_D$                    | 13.5 | A          |
| $Q_g$                    | 19   | nC         |



Schematic diagram

✧ Intrinsic fast-recovery body diode

### Package Marking And Ordering Information

| Device     | Device Package | Marking    |
|------------|----------------|------------|
| NCE50NF220 | TO-220         | NCE50NF220 |



Table 1. Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ )

| Parameter   | Symbol          | Value      | Unit                |
|---|-----------------|------------|---------------------|
| Drain-Source Voltage ( $V_{GS}=0V$ )                                | $V_{DS}$        | 500        | V                   |
| Gate-Source Voltage ( $V_{DS}=0V$ ), AC ( $f>1\text{ Hz}$ )         | $V_{GS}$        | $\pm 30$   | V                   |
| Gate-Source Voltage ( $V_{DS}=0V$ ), DC                             | $V_{GS}$        | $\pm 20$   | V                   |
| Continuous Drain Current at $T_c=25^\circ\text{C}$                  | $I_{D(DC)}$     | 13.5       | A                   |
| Continuous Drain Current at $T_c=100^\circ\text{C}$                 | $I_{D(DC)}$     | 9.45       | A                   |
| Pulsed drain current (Note 1)                                       | $I_{DM(pluse)}$ | 40.5       | A                   |
| Maximum Power Dissipation( $T_c=25^\circ\text{C}$ )                 | $P_D$           | 109        | W                   |
| Derate above $25^\circ\text{C}$                                     |                 | 0.72       | W/ $^\circ\text{C}$ |
| Single pulse avalanche current (Note 2)                             | $I_{AS}$        | 3          | A                   |
| Reverse diode $dv/dt$ , $V_{DS} \leq 480\text{ V}$ , $I_{SD} < I_D$ | $dv/dt$         | 15         | V/ns                |
| Drain Source voltage slope, $V_{DS} \leq 480\text{ V}$              | $dv/dt$         | 50         | V/ns                |
| Operating Junction and Storage Temperature Range                    | $T_J, T_{STG}$  | -55...+175 | $^\circ\text{C}$    |

**Table 2. Thermal Characteristic**

| Parameter   | Symbol     | Value | Unit                        |
|---|------------|-------|-----------------------------|
| Thermal Resistance, Junction-to-Case (Maximum)    | $R_{thJC}$ | 1.37  | $^{\circ}\text{C}/\text{W}$ |
| Thermal Resistance, Junction-to-Ambient (Maximum) | $R_{thJA}$ | 62    | $^{\circ}\text{C}/\text{W}$ |

**Table 3. Electrical Characteristics (TA=25°C unless otherwise noted)**

| Parameter                                | Symbol              | Condition  | Min | Typ  | Max  | Unit |
|--|---------------------|--|-----|------|------|------|
| On/off states                            |                     |  |     |      |      |      |
| Drain-Source Breakdown Voltage           | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V I <sub>D</sub> =250uA  | 500 |      |      | V    |
| Zero Gate Voltage Drain Current(Tc=25℃)  | I <sub>DSS</sub>    | V <sub>DS</sub> =500V,V <sub>GS</sub> =0V  |     |      | 10   | μA   |
| Zero Gate Voltage Drain Current(Tc=125℃) | I <sub>DSS</sub>    | V <sub>DS</sub> =500V,V <sub>GS</sub> =0V  |     |      | 100  | μA   |
| Gate-Body Leakage Current                | I <sub>GSS</sub>    | V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V  |     |      | ±200 | nA   |
| Gate Threshold Voltage                   | V <sub>GS(th)</sub> | V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250uA                                | 3   |      | 5    | V    |
| Drain-Source On-State Resistance         | R <sub>DS(ON)</sub> | V <sub>GS</sub> =10V, I <sub>D</sub> =6.5A   |     | 180  | 220  | mΩ   |
| Dynamic Characteristics                  |                     |  |     |      |      |      |
| Gate Resistance                          | R <sub>g</sub>      | F=1MHZ, D-S short  |     | 15   |      | Ω    |
| Input Capacitance                        | C <sub>iss</sub>    | V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,<br>F=1MHz                                    |     | 846  |      | pF   |
| Output Capacitance                       | C <sub>oss</sub>    |  |     | 46   |      | pF   |
| Reverse Transfer Capacitance             | C <sub>rss</sub>    |  |     | 1.8  |      | pF   |
| Total Gate Charge                        | Q <sub>g</sub>      | V <sub>DS</sub> =380V,I <sub>D</sub> =6.5A,<br>V <sub>GS</sub> =10V                    |     | 19   |      | nC   |
| Gate-Source Charge                       | Q <sub>gs</sub>     |  |     | 7.3  |      | nC   |
| Gate-Drain Charge                        | Q <sub>gd</sub>     |  |     | 5.7  |      | nC   |
| Gate plateau voltage                     | V <sub>gp</sub>     |  |     | 6.6  |      | V    |
| Switching times                          |                     |  |     |      |      |      |
| Turn-on Delay Time                       | t <sub>d(on)</sub>  | V <sub>DD</sub> =380V,I <sub>D</sub> =6.5A,<br>R <sub>G</sub> =4Ω,V <sub>GS</sub> =10V |     | 8    |      | nS   |
| Turn-on Rise Time                        | t <sub>r</sub>      |  |     | 10   |      | nS   |
| Turn-Off Delay Time                      | t <sub>d(off)</sub> |  |     | 41   |      | nS   |
| Turn-Off Fall Time                       | t <sub>f</sub>      |  |     | 10   |      | nS   |
| Source- Drain Diode Characteristics      |                     |  |     |      |      |      |
| Source-drain current(Body Diode)         | I <sub>SD</sub>     | T <sub>C</sub> =25℃  |     |      | 13.5 | A    |
| Pulsed-Source-drain current(Body Diode)  | I <sub>SDM</sub>    |  |     |      | 40.5 | A    |
| Forward on voltage                       | V <sub>SD</sub>     | T <sub>j</sub> =25℃,I <sub>SD</sub> =13.5A,V <sub>GS</sub> =0V                         |     | 1.0  | 1.2  | V    |
| Reverse Recovery Time                    | t <sub>rr</sub>     | T <sub>j</sub> =25℃,I <sub>F</sub> =6.5A,<br>di/dt=100A/μs                             |     | 150  |      | nS   |
| Reverse Recovery Charge                  | Q <sub>rr</sub>     |  |     | 0.34 |      | uC   |
| Peak reverse recovery current            | I <sub>rrm</sub>    |  |     | 4.5  |      | A    |

Notes: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2.  $T_j=25^{\circ}\text{C}, V_{DD}=50V, V_G=10V, R_G=25\Omega$

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Output characteristics

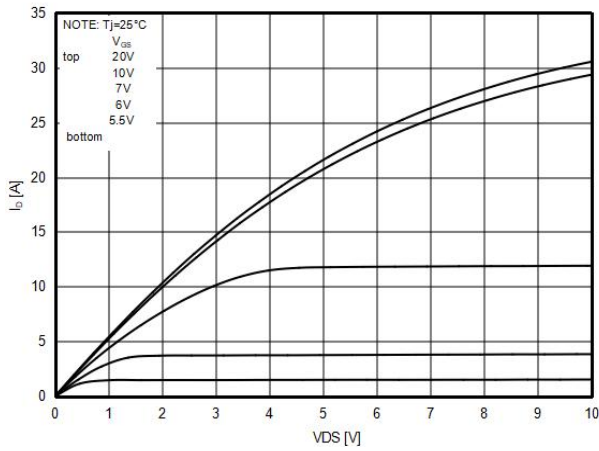


Figure2. Transfer characteristics

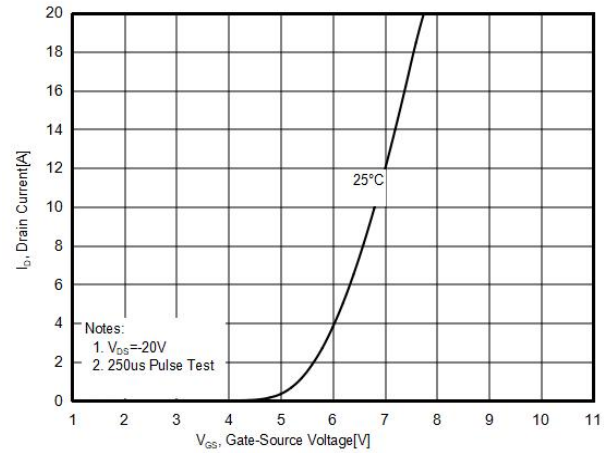


Figure3.  $R_{DS(ON)}$  vs Junction Temperature

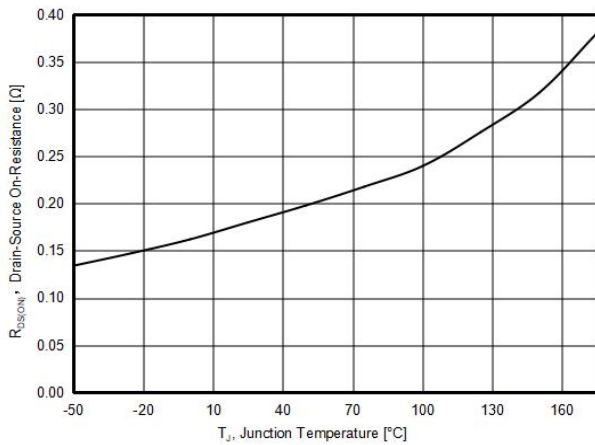


Figure4.  $BV_{DSS}$  vs Junction Temperature

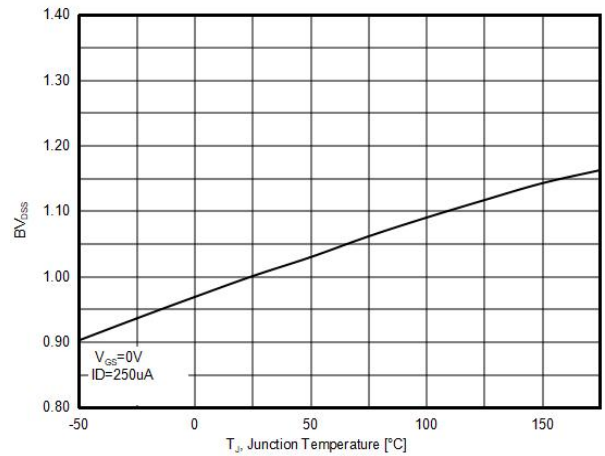


Figure5. Maximum  $I_D$  vs Junction Temperature

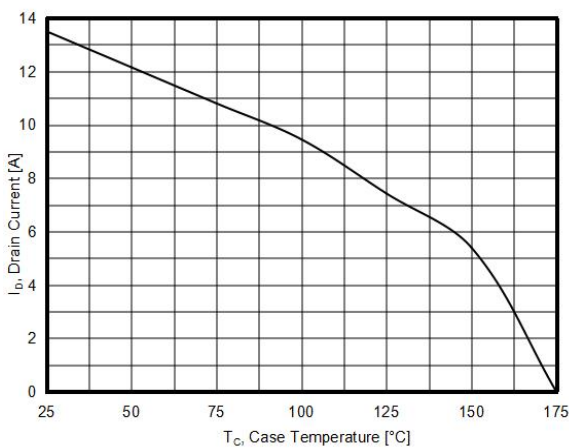


Figure6. Gate charge waveforms

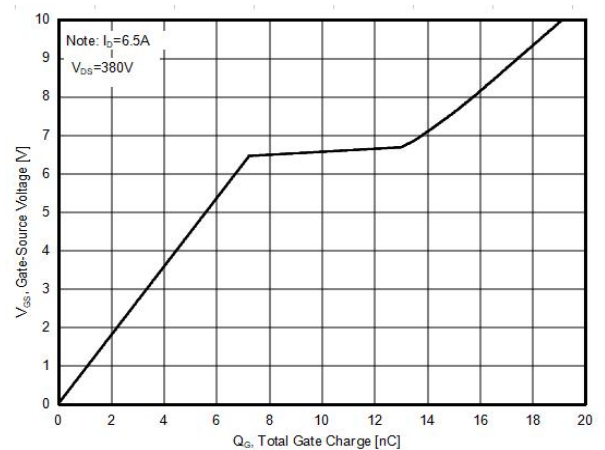


Figure7. Static drain-source on resistance

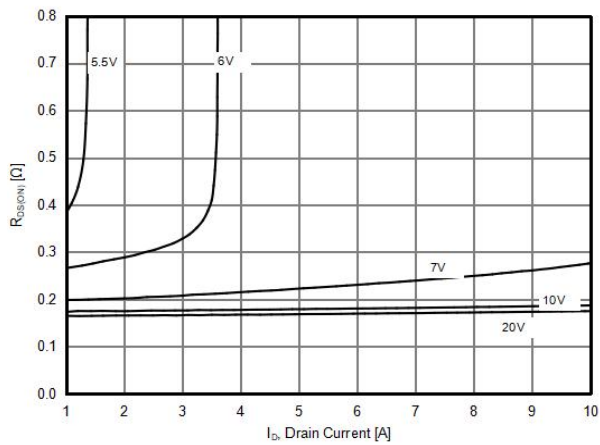


Figure8. Source-Drain Diode Forward Voltage

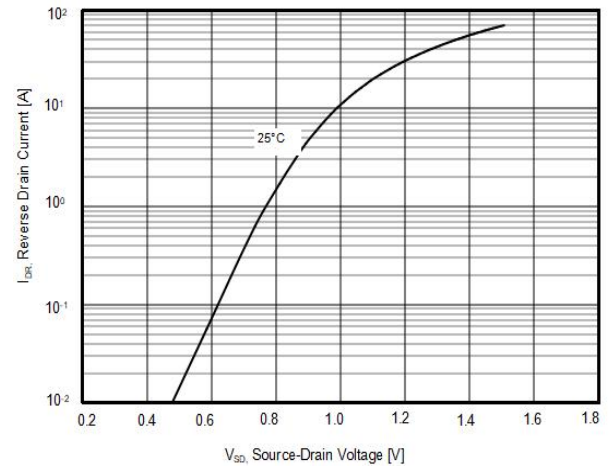


Figure9. Capacitance

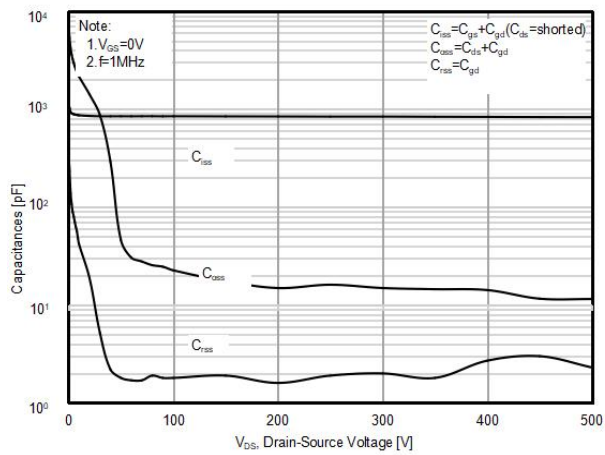
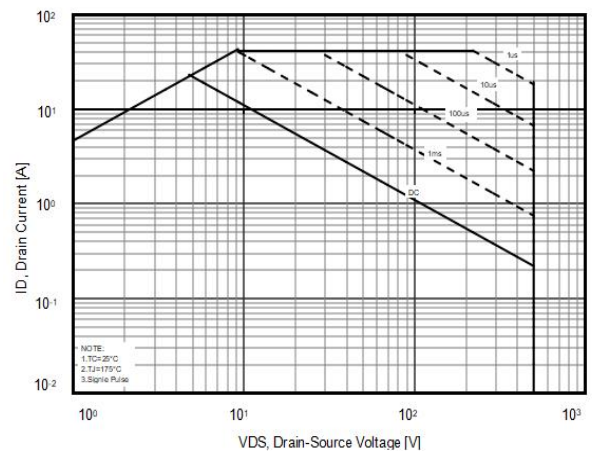
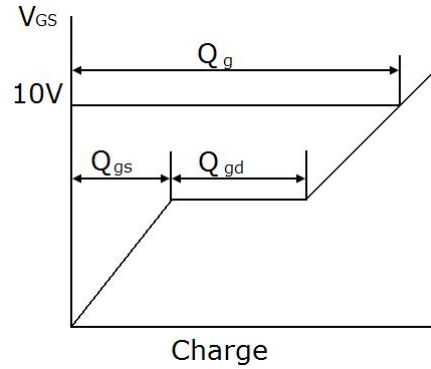
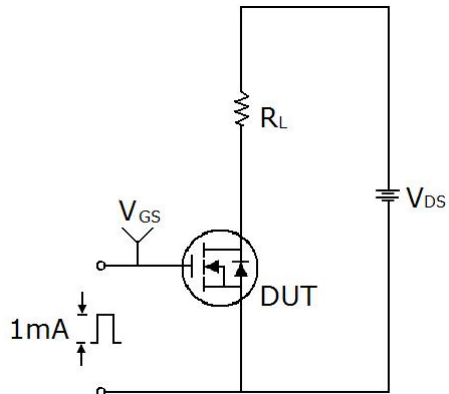


Figure10. Safe operating area

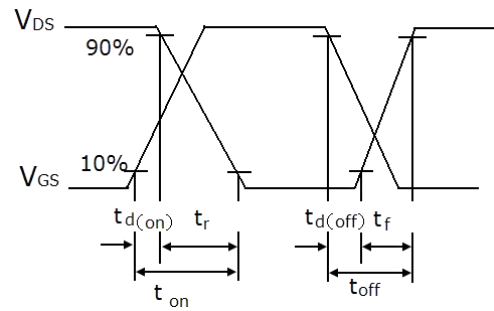
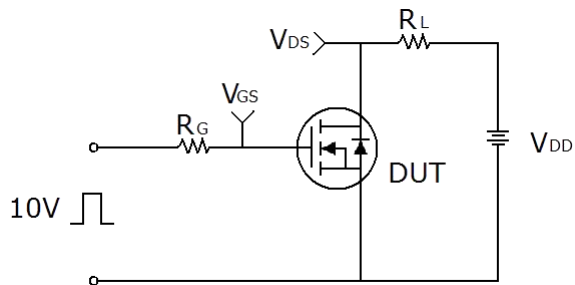


## Test circuit

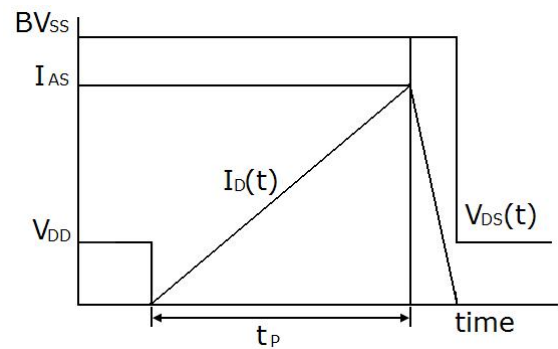
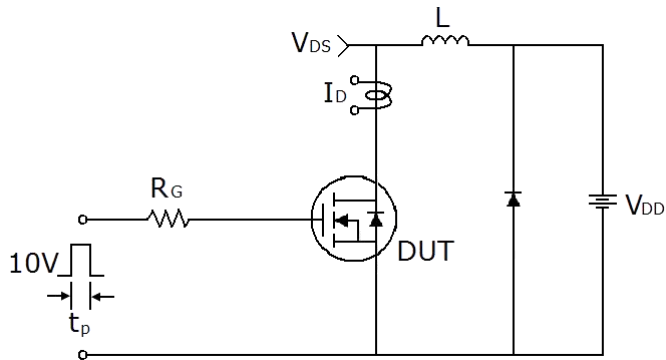
### 1) Gate charge test circuit & Waveform



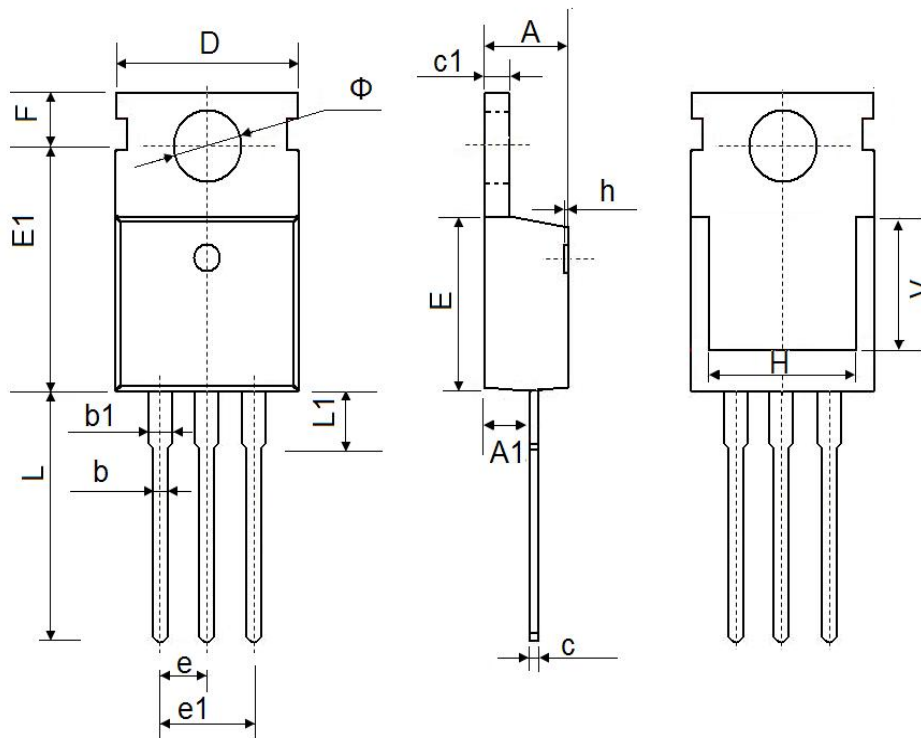
### 2) Switch Time Test Circuit:



### 3) Unclamped Inductive Switching Test Circuit & Waveforms

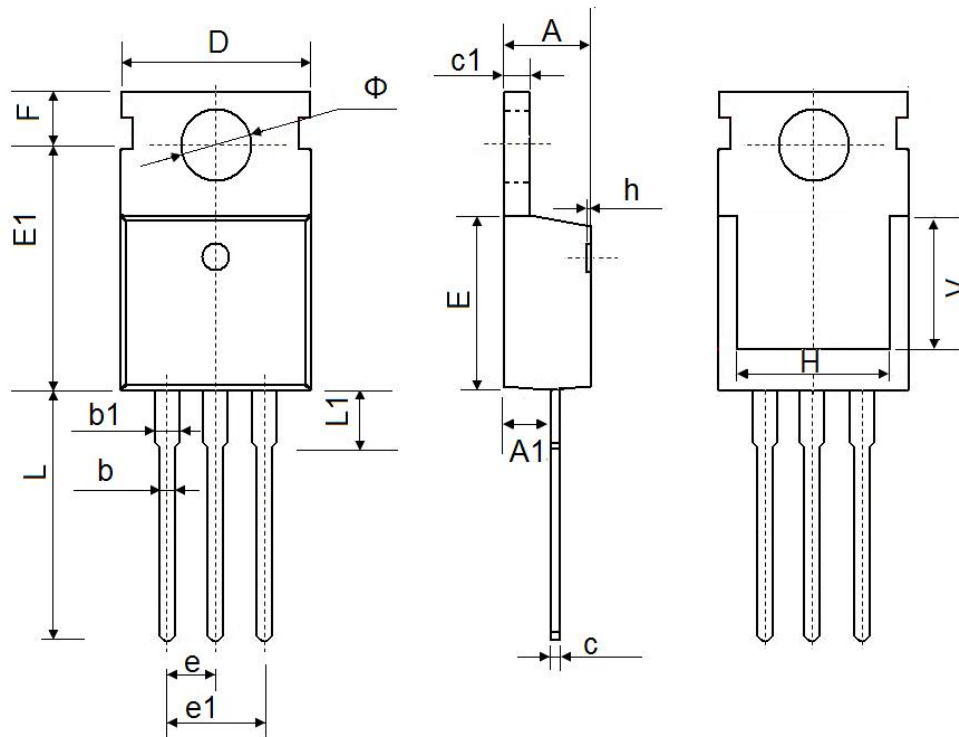


## TO-220-E Package Information



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 4.20                      | 4.60  | 0.165                | 0.181 |
| A1     | 2.25                      | 2.55  | 0.089                | 0.100 |
| b      | 0.70                      | 0.90  | 0.028                | 0.035 |
| b1     | 1.17                      | 1.37  | 0.046                | 0.054 |
| c      | 0.33                      | 0.65  | 0.013                | 0.026 |
| c1     | 1.20                      | 1.40  | 0.047                | 0.055 |
| D      | 9.91                      | 10.25 | 0.390                | 0.404 |
| E      | 8.95                      | 9.75  | 0.352                | 0.384 |
| E1     | 12.80                     | 12.90 | 0.504                | 0.508 |
| e      | 2.54BSC                   |       | 0.100BSC             |       |
| e1     | 5.08BSC                   |       | 0.200BSC             |       |
| F      | 2.65                      | 2.95  | 0.104                | 0.116 |
| H      | 7.90                      | 8.10  | 0.311                | 0.319 |
| L      | 12.90                     | 13.40 | 0.508                | 0.528 |
| L1     | 2.85                      | 3.25  | 0.112                | 0.128 |
| Φ      | 3.40                      | 3.80  | 0.134                | 0.150 |

## TO-220-S Package Information



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 4.4                       | 4.6   | 0.173                | 0.181 |
| A1     | 2.25                      | 2.55  | 0.089                | 0.1   |
| b      | 0.71                      | 0.91  | 0.028                | 0.036 |
| b1     | 1.17                      | 1.37  | 0.046                | 0.054 |
| c      | 0.33                      | 0.65  | 0.013                | 0.026 |
| c1     | 1.2                       | 1.4   | 0.047                | 0.055 |
| D      | 9.91                      | 10.25 | 0.39                 | 0.404 |
| E      | 8.95                      | 9.75  | 0.352                | 0.384 |
| E1     | 12.65                     | 12.95 | 0.498                | 0.51  |
| e      | 2.540 TYP.                |       | 0.100 TYP.           |       |
| e1     | 4.98                      | 5.18  | 0.196                | 0.204 |
| F      | 2.65                      | 2.95  | 0.104                | 0.116 |
| H      | 7.9                       | 8.1   | 0.311                | 0.319 |
| h      | 0                         | 0.3   | 0                    | 0.012 |
| L      | 12.9                      | 13.4  | 0.508                | 0.528 |
| L1     | 2.85                      | 3.25  | 0.112                | 0.128 |
| V      | 7.500 REF.                |       | 0.295 REF.           |       |
| Φ      | 3.4                       | 3.8   | 0.134                | 0.15  |

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